

#### PNP SURFACE MOUNT TRANSISTOR

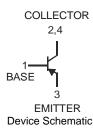
### **Features**

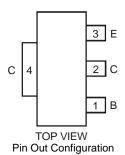
- **Epitaxial Planar Die Construction**
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

### **Mechanical Data**

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.055 grams (approximate)







### Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Continuous Collector Current	Ic	-2	А
Base Current	I <sub>B</sub>	-0.4	A

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T <sub>A</sub> = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
  Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



## Electrical Characteristics @TA = 25°C unless otherwise specified

Charac	cteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTIC	OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage		V <sub>(BR)CBO</sub>	-50	_	_	V	$I_C = -100 \mu A$ , $I_E = 0$
Collector-Emitter Breakdo	own Voltage	V <sub>(BR)CEO</sub>	-50	_	_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown	Voltage	V <sub>(BR)EBO</sub>	-5	_	_	V	$I_E = -100 \mu A, I_C = 0$
Collector Cut-Off Current		I <sub>CBO</sub>	_	_	-0.1	μΑ	$V_{CB} = -50V, I_E = 0$
Emitter Cut-Off Current		I <sub>EBO</sub>	_	_	-0.1	μΑ	$V_{EB} = -5V, I_{C} = 0$
ON CHARACTERISTICS	(Note 4)						
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>			-0.5	V	$I_C = -1A$ , $I_B = -50mA$
Base-Emitter Saturation Voltage		V <sub>BE(SAT)</sub>			-1.2	V	$I_C = -1A$ , $I_B = -50mA$
	2DA1213O		70	_	140	_	$V_{CE} = -2V, I_{C} = -0.5A$
DC Current Gain	2DA1213Y	h <sub>FE</sub>	120	_	240	_	$V_{CE} = -2V, I_{C} = -0.5A$
	2DA1213O, 2DA1213Y	]	20		_		V <sub>CE</sub> = -2V, I <sub>C</sub> = -2A
SMALL SIGNAL CHARA	SMALL SIGNAL CHARACTERISTICS						
Transition Frequency		$f_T$	_	160		MHz	$V_{CE} = -2V$ , $I_{C} = -100$ mA, $f = 100$ MHz
Output Capacitance		C <sub>obo</sub>	_	17	_	pF	$V_{CB} = -10V$ , $I_{E} = 0$ , $f = 1MHz$
SWITCHING CHARACTERISTICS							
Turn-On Time		t <sub>on</sub>	_	25		ns	V 2V I 4A
Storage Time		ts		130	_	ns	$V_{CE} = -2V, I_{C} = -1A,$
Fall Time		t <sub>f</sub>	_	12	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$

Notes: 4. Measured under pulsed conditions. Pulse width =  $300\mu s$ . Duty cycle  $\leq 2\%$ .

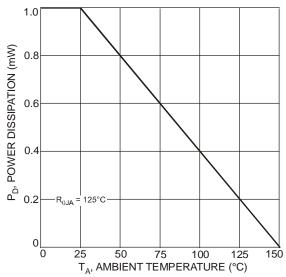


Fig. 1 Power Dissipation vs. Ambient Temperature

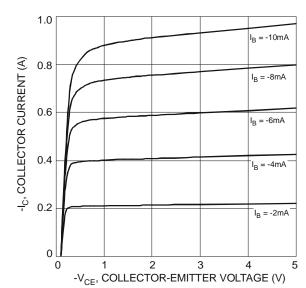
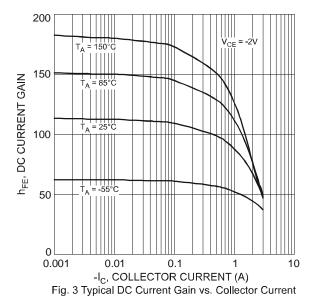
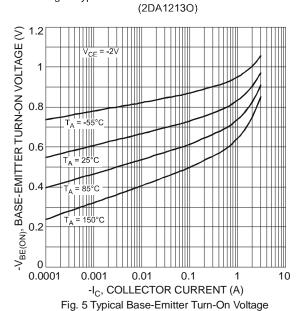
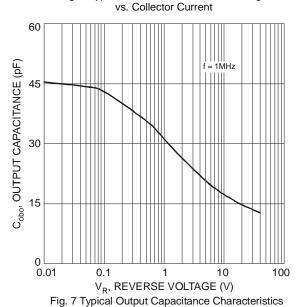


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage









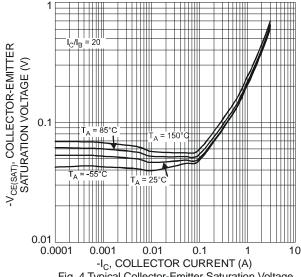


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

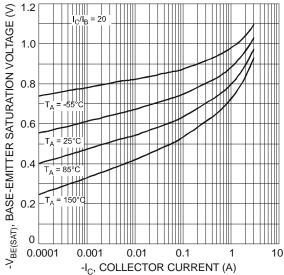


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

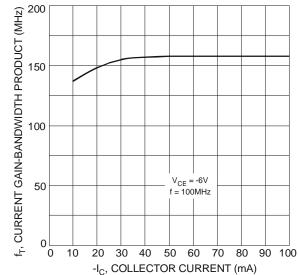


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

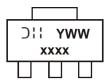


## Ordering Information (Note 5)

Part Number	Case	Packaging
2DA1213O-13	SOT89-3L	2500/Tape & Reel
2DA1213Y-13	SOT89-3L	2500/Tape & Reel

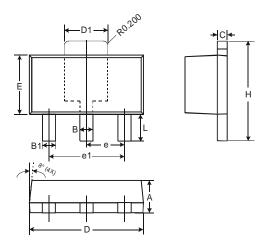
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



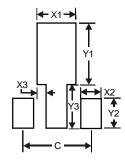
xxxx = Product Type Marking Code: P25X = 2DA1213O P25Y = 2DA1213Y YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code 01 - 53

## **Package Outline Dimensions**



SOT89-3L				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
E	2.29	2.60		
e 1.50 Typ				
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**



<b>Dimensions</b>	Value (in mm)
X1	1.7
X2	0.9
Х3	0.4
Y1	2.7
Y2	1.3
Y3	1.9
С	3.0



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